



Date: 12th October 2015

Data Sheet Issue: 1

# Dual Diode Modules MD#630-30N2 & MD#630-36N2

**Absolute Maximum Ratings** 

V <sub>RRM</sub>	MDD MDD	MDA	MDK
1200	630-30N2	630-30N2	630-30N2
1800	630-36N2	630-36N2	630-36N2

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
$V_{RRM}$	Repetitive peak reverse voltage 1)	3000-3600	V
V <sub>RSM</sub>	Non-repetitive peak reverse voltage 1)	3100-3700	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
I <sub>F(AV)M</sub>	Maximum average on-state current, T <sub>C</sub> = 85°C <sup>2)</sup>	630	Α
$I_{F(AV)M}$	Maximum average on-state current. T <sub>C</sub> = 100°C <sup>2)</sup>	530	Α
I <sub>F(RMS)M</sub>	Nominal RMS on-state current, T <sub>C</sub> = 55°C <sup>2)</sup>	1275	Α
I <sub>F(d.c.)</sub>	D.C. on-state current, T <sub>C</sub> = 55°C	1090	Α
I <sub>FSM</sub>	Peak non-repetitive surge t <sub>p</sub> = 10 ms, V <sub>RM</sub> = 60%V <sub>RRM</sub> <sup>3)</sup>	11.7	kA
I <sub>FSM2</sub>	Peak non-repetitive surge $t_p = 10$ ms, $V_{RM} \le 10V^{3}$	13.0	kA
l <sup>2</sup> t	$I^{2}t$ capacity for fusing $t_{p} = 10$ ms, $V_{RM} = 60\%V_{RRM}$ <sup>3)</sup>	845×10 <sup>3</sup>	A <sup>2</sup> s
l <sup>2</sup> t	$I^{2}t$ capacity for fusing $t_{p}$ = 10 ms, $V_{RM} \le 10 \text{ V}^{3}$	684×10 <sup>3</sup>	A <sup>2</sup> s
Visol	Isolation Voltage 4)	3000	V
T <sub>vj op</sub>	Operating temperature range	-40 to +150	°C
T <sub>stg</sub>	Storage temperature range	-40 to +150	°C

#### Notes

- 1) De-rating factor of 0.13% per °C is applicable for  $T_{v_j}$  below 25°C.
- 2) Single phase; 50 Hz, 180° half-sinewave.
- 3) Half-sinewave, 150°C T<sub>vj</sub> initial.
- 4) AC RMS voltage, 50 Hz, 1min test



# **Characteristics**

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS 1)	UNITS
V <sub>FM</sub>	Maximum peak forward voltage	-	-	1.20	I <sub>FM</sub> = 800 A	V
$V_{FM}$	Maximum peak forward voltage	-	-	1.80	I <sub>FM</sub> = 2000 A	V
V <sub>T0</sub>	Threshold voltage	-	-	0.80		V
r⊤	Slope resistance	-	-	0.50		mΩ
I <sub>RRM</sub>	Peak reverse current	-	-	50	Rated V <sub>RRM</sub>	mA
Qrr	Recovered Charge	-	2900	3200		μC
Qra	Recovered Charge, 50% chord	-	2560	-	  I <sub>TM</sub> = 500A, t <sub>P</sub> =1ms, di/dt =10A/μs,	μC
I <sub>rm</sub>	Reverse recovery current	-	150	-	V <sub>R</sub> =100 V	Α
t <sub>rr</sub>	Reverse recovery time, 50% chord	-	34	-		μs
0	The armed anniation of the state of the stat	-	-	0.0650	Single Diode	K/W
$R_{thJC}$	Thermal resistance, junction to case	-	-	0.0325	Whole Module	K/W
0	The second secon	-	-	0.02	Single Diode	K/W
RthCH	Thermal resistance, case to heatsink	-	-	0.01	Whole Module	K/W
F <sub>1</sub>	Mounting force (to heatsink) 2)	5.1	-	6.9		Nm
F <sub>2</sub>	Mounting force (to terminals) 2)	10.2	-	13.8		Nm
Wt	Weight	-	1.5	-		kg

## Notes:

- Unless otherwise indicated T<sub>vj</sub>=150°C.
  Screws must be lubricated.



#### **Notes on Ratings and Characteristics**

#### 1.0 Voltage Grade Table

Voltage Grade	V <sub>RRM</sub> V	V <sub>RSM</sub> V	V <sub>R</sub> DC V
3000	3000	3100	2250
3600	3600	3700	2700

# 2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

#### 3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T<sub>vi</sub> below 25°C.

#### 4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

#### 5.0 Computer Modelling Parameters

#### 5.1 Thyristor Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{{V_{T0}}^2 + 4 \cdot \textit{ff}^2 \cdot \textit{r}_T \cdot W_{AV}}}{2 \cdot \textit{ff}^2 \cdot \textit{r}_T} \qquad \qquad W_{AV} = \frac{\Delta T}{R_{th}}$$
 and: 
$$\Delta T = T_{j \max} - T_K$$

Where  $V_{T0} = 0.80 \text{ V}$ ,  $r_T = 0.50 \text{ m}\Omega$ .

 $R_{th}$  = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance							
Conduction Angle      30°      60°      90°      120°      180°      270°      d.c.						d.c.	
Square wave	0.0798	0.0742	0.0712	0.0694	0.0674	0.0659	0.0650
Sine wave	0.0736	0.0685	0.0667	0.0657	0.0651		

Form Factors							
Conduction Angle	30°	60°	90°	120°	180°	270°	d.c.
Square wave	3.464	2.449	2	1.732	1.414	1.149	1
Sine wave	3.98	2.778	2.22	1.879	1.57		



## 5.2 Calculating diode V<sub>F</sub> using ABCD Coefficients

The forward characteristic I<sub>F</sub> vs. V<sub>F</sub>, on page 6 is represented by a set of constants A, B, C, D, forming the coefficients of the representative equation for V<sub>F</sub> in terms of I<sub>F</sub> given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for  $V_F$  agree with the true device characteristic over a current range, which is limited to that plotted.

25°C Coefficients		150°C Coefficients		
Α	0.8507456	Α	0.4945386	
В	0.04762876	В	0.05726181	
С	4.08857×10 <sup>-4</sup>	С	4.98169×10 <sup>-4</sup>	
D	-3.12768×10 <sup>-3</sup>	D	-2.79389×10 <sup>-3</sup>	

#### 5.3 D.C. Thermal Impedance Calculation

$$r_{t} = \sum_{p=1}^{p=n} r_{p} \cdot \left(1 - e^{\frac{-t}{\tau_{p}}}\right)$$

Where p = 1 to n and:

n = number of terms in the series

t = Duration of heating pulse in seconds

rt = Thermal resistance at time t

 $r_p$  = Amplitude of  $p_{th}$  term

 $\tau_D$  = Time Constant of  $r_{th}$  term

The coefficients for this device are shown in the table below:

D.C. Single Diode								
Term	Term 1 2 3 4							
$r_p$	0.03671713	0.01198766	0.01439901	1.895749×10 <sup>-3</sup>				
$ au_{\mathcal{P}}$	3.123905	0.8540715	0.1955971	1.412289×10 <sup>-3</sup>				



## 6.0 Reverse recovery ratings

(i)  $Q_{\text{ra}}$  is based on 50%  $I_{\text{RM}}$  chord as shown in Fig. 1

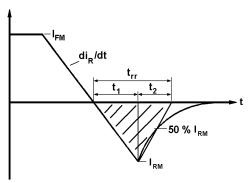


Fig. 1

(ii)  $Q_{\text{rr}}$  is based on a 150  $\mu s$  integration time i.e.

$$Q_{rr} = \int_{0}^{150\mu s} i_{rr}.dt$$

(iii) 
$$K Factor = \frac{t_1}{t_2}$$



## **Curves**

Figure 1 – Forward characteristics of Limit device

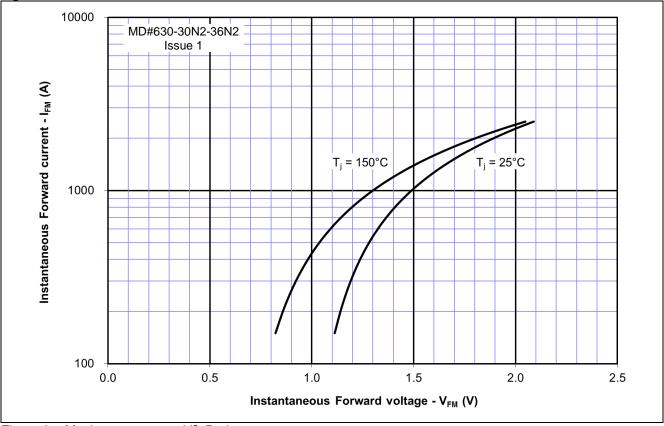


Figure 2 – Maximum surge and I<sup>2</sup>t Ratings

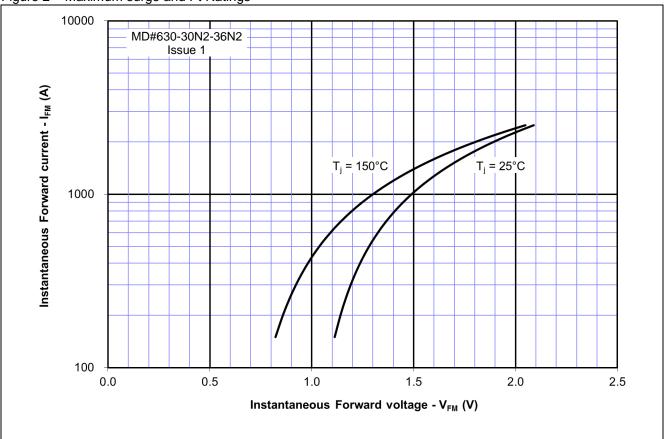




Figure 3 - Total recovered charge, Qrr

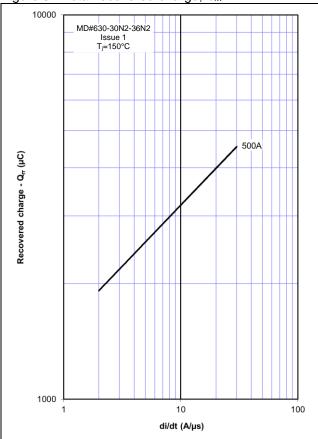
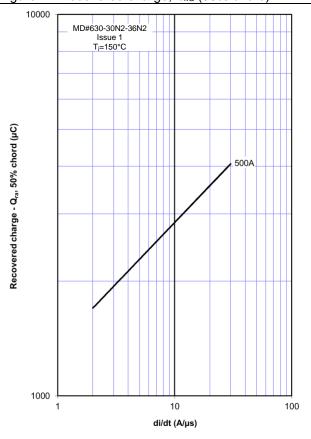


Figure 4 - Recovered charge, Q<sub>ra</sub> (50% chord)



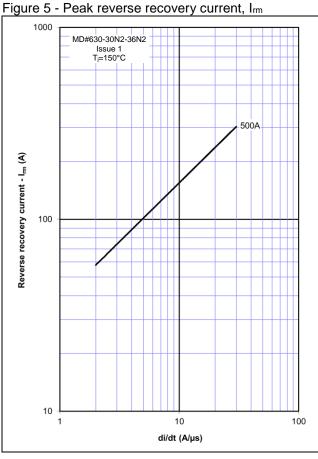


Figure 6 - Maximum recovery time, trr (50% chord)

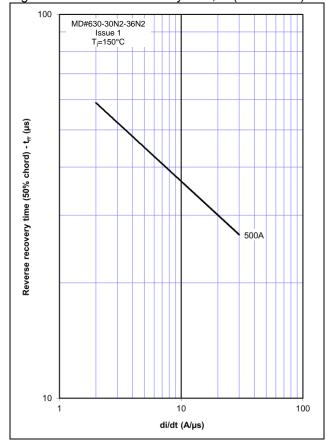




Figure 7 – Forward current vs. Power dissipation

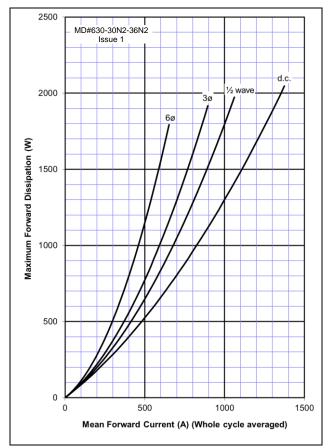
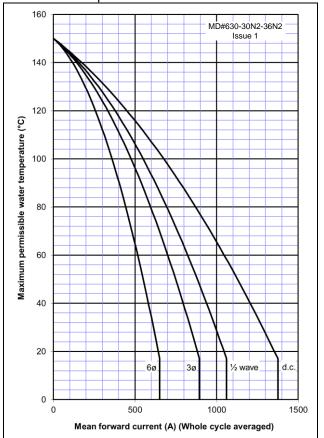
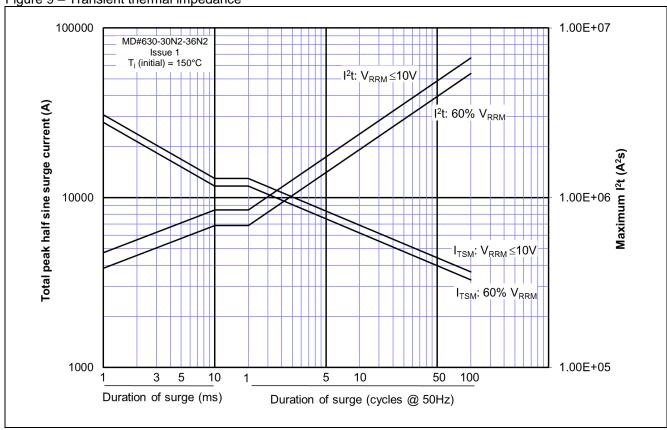


Figure 8 – Forward current vs. Heatsink temperature

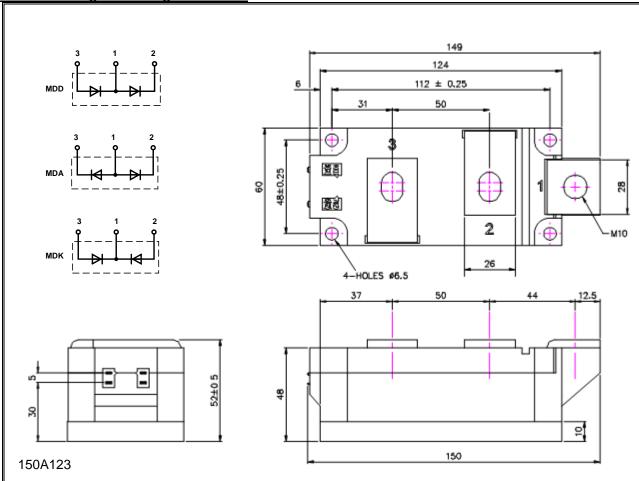








## **Outline Drawing & Ordering Information**



	ORDERING INFO	RMATION	(Please quote 11 digit code as below)		
M	D#	630	<b>*</b> *	N	2
Fixed Type Code	Configuration code DD, DA, DK	Fixed Type Code	Voltage code V <sub>RRM</sub> /100 30-36	Standard Diode	Fixed Version Code

Typical order code: MDA630-36N2- MDA configuration, 6600V  $V_{\text{RRM}}$ 

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